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Tyco Electronics SiBar[™] Thyristor Surge Protectors **TVAxxxRSA-L Series**

Circuit Protection's SiBar thyristor surge protection devices are designed to help protect sensitive telecommunication equipment from the hazards caused by lightning, power contact, and power induction. These devices have a high electrical surge capability to help protect against transient faults and a high off-state impedance, rendering them virtually transparent during normal system operation.

SiBar thyristor surge protectors are designed to assist telecommunication and computer telephony equipment in meeting the applicable requirements and industry specifications.



Benefits:

- · Helps provide protection for sensitive telecom electronic equipment
- · Lower capacitance
- · Low leakage current
- · Low power dissipation
- · Fast, reliable operation
- · No wear-out mechanisms
- · Helps designers meet worldwide telecom standards
- · Helps reduce warranty and service costs
- · Easy installation
- · Helps improve power efficiency of equipment

Features:

- · RoHS compliant
- · Bidirectional crowbar transient voltage protection
- Broad voltage range 65V 320V
- Low capacitance 12pF 20pF @ 50V
- · High off-state impedance
- · Low on-state voltage
- · High surge capability
- · Short-circuit failure mode
- · Surface-mount technology
- · DO-214AC SMA package
- 10 x 1000 µs 50A surge rating
- Helps equipment comply with TIA-968, Telcordia GR-1089, IEC61000-4-5, ITU K.20/21/45

Applications:

· Modems

- · Set top boxes
- · Fax machines
- · POS systems
- · Phones, answering machines
- · Analog and digital linecards (xDSL, T1/E1, ISDN...)

· PBX systems

· Other customer premise and central office network equipment requiring

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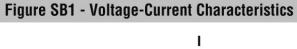
Table SB1 - E	lectrical Cha	aracteristics					
Part Number	V _{DM} Max. (V)	V _{BO} Max. (V)	I _H Min. (mA)	V _⊤ Max. (V)	C1 (Typ) @ 50V _{DC} Bias (pF)	C2 (Typ) @ 2V _{DC} Bias (pF)	Off-State Current @VDM (µA)
TVA065RSA-L	65	88	150	4	20	40	5
TVA090RSA-L	90	130	150	4	20	40	5
TVA120RSA-L	120	160	150	4	16	30	5
TVA130RSA-L	130	173	150	4	14	30	5
TVA170RSA-L	170	220	150	4	14	25	5
TVA190RSA-L	190	260	150	4	14	25	5
TVA220RSA-L	220	295	150	4	12	25	5
TVA270RSA-L	275	350	150	4	12	25	5
TVA300RSA-L	320	400	150	4	12	25	5

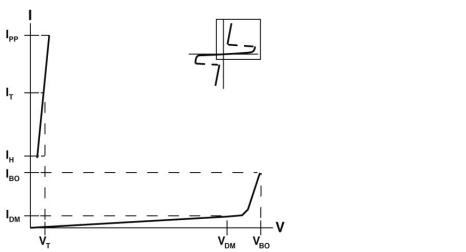
Notes: All electrical characteristics are measured at 25°C.
V_{DM} measured per UL497B pulse requirements: at max. off-state leakage current (IDM) = 5 μA.

V_{BO} measured at 100V/μs.

Table SB2	2 – Surge	Current Ra	ating							
	TIA-968			Telcordia GI	R-1089*	IEC61000-4-5	ITU K.20/21/45*			
	Type A	Type B						_		
Part Number	I _{pp} (A) 5 x 320 μs	I _{pp} (A) 10 x 560 μs	_{pp} (A) 10 х 160 µs	I _{pp} (Α) 10 x 1000 μs	I _{pp} (A) s 2 x 10 μs	Ι _{pp} (A) 8 x 20 μs	I _{PP} (A) 5 x 310 μs (VOC: 10 x 700μs)	I _{TSM} Min. (A)	di/dt (A/µs)	dV/dt (V/μs)
TVAxxxRSA-L	65	55	75	50	100	100	65	22	500	2000

Notes: *Lightning current wave forms for applicable industry specification. I_{ISM} , peak on-state surge current is measured at 60 Hz, one cycle. di/dt: critical rate-of-rise of on-state current (pulsed power amplifier Vmax = 600V; C = 30 μ F). dV/dt: critical rate-of-rise of off-stage voltage (linear wave form, V_0 = rated V_{BO} , T_1 = 25°C)





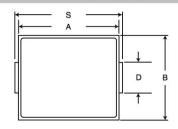
The voltage current (V-I) is useful in depicting the electrical characteristics of the SiBar thyristor surge protectors in relation to each other.

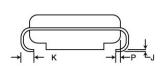
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Figure SB2 - Dimension Figure





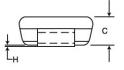


Table SB3 - Dimensions in Millimeters

	Α		В		С		D	
Dimension	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.
TVAxxxRSA-L	4.06	4.57	2.25	2.92	1.90	2.41	1.25	1.65
I VAXXXROA-L	(0.160)	(0.180)	(0.089)	(0.115)	(0.075)	(0.095)	(0.049)	(0.065)

	Н		J		К		Р	S	
Dimension	Min.	Max.	Min.	Max.	Min.	Max.	Ref	Min	Max.
TVAxxxRSA-L	0.051	0.200	0.150	0.41	0.76	1.52	0.51	4.80	5.59
TVAXXXRSA-L	(0.002)	(0.008)	(0.006)	(0.016)	(0.030)	(0.060)	(0.020)	(0.189)	(0.220)

Notes: *D dimension is measured within dimension P.

TVA series devices use industry standard SMA package type.

All devices are bidirectional and may be oriented in either direction for installation

Table SB4 – Physical Characteristics and Er	vironmental Specifications
Lead material	Matte tin finish (-L devices)
Encapsulating material	Epoxy, meets UL94V-0 requirements
Solderability	per MIL-STD-750, Method 2026
Solder heat withstand	per MIL-STD-750, Method 2031
Solvent resistance	per MIL-STD-750, Method 1022
Mechanical shock	per MIL-STD-750, Method 2016
Vibration	per MIL-STD-750, Method 2056
Storage temperature (°C)	-55 to 150
Operating temperature (°C)	-40 to 125
Max Junction temperature (°C)	150
Maximum Lead Temperature for Soldering Purpose; for 10s (°C)	260

Test	Conditions	Duration
High temperature, reverse bias	+100°C, 50VDC bias	1000 hours
High humidity, high temperature, reverse bias	85% RH, +85°C, 50VDC bias	1000 hours
High temperature storage life	+150°C	1000 hours
Temperature cycling	-65°C to +150°C, 15 minute dwell	1000 cycles
Autoclave	100% RH, +121°C, 15 PSI	96 hours

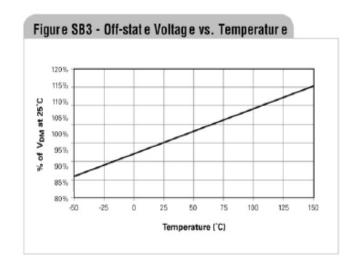
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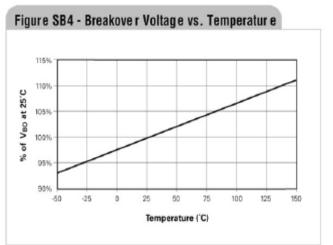
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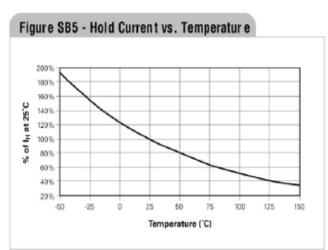


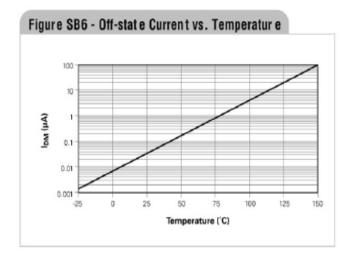
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Figures SB3-SB6 - Typical Electrical Charateristics vs. Temperature for Sibar Thyristor Surge Protectors



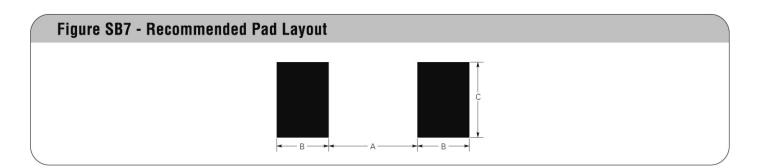








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				Recommended Pad Layout (millimeters/inchs)						
Part Description	Tape and Reel Quantity	Standard Package	Part Marking	Dimension A (Nom.)	Dimension B (Nom.)	Dimension C (Nom.)	Agency Recognition*			
TVA065RSA-L	5,000	20,000	A065	2.00 (0.079)	2.00 (0.079)	2.00 (0.079)	UL			
TVA090RSA-L	5,000	20,000	A090	2.00 (0.079)	2.00 (0.079)	2.00 (0.079)	UL			
TVA120RSA-L	5,000	20,000	A120	2.00 (0.079)	2.00 (0.079)	2.00 (0.079)	UL			
TVA130RSA-L	5,000	20,000	A130	2.00 (0.079)	2.00 (0.079)	2.00 (0.079)	UL			
TVA170RSA-L	5,000	20,000	A170	2.00 (0.079)	2.00 (0.079)	2.00 (0.079)	UL			
TVA190RSA-L	5,000	20,000	A190	2.00 (0.079)	2.00 (0.079)	2.00 (0.079)	UL			
TVA220RSA-L	5,000	20,000	A220	2.00 (0.079)	2.00 (0.079)	2.00 (0.079)	UL			
TVA270RSA-L	5,000	20,000	A270	2.00 (0.079)	2.00 (0.079)	2.00 (0.079)	UL			
TVA300RSA-L	5,000	20,000	A300	2.00 (0.079)	2.00 (0.079)	2.00 (0.079)	**			



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